深圳市炬烜科技有限公司

CHIP SUN TECHNOLOGY CO., LTD

APPROVAL SHEET

RoHS Compliant

(Seam Type)

CUSTOMER：

DESCRIPTION：SMD3225 16.000MHz Quartz Crystal Resonator

MANUFACTURER PART NO.: FTX16.000M20SM3S-30/30DEW

CUSTOMER PART NO:

USED IN MODEL:

REVISION A1

承　　认　　APPROVAL		
工程部 TECHNOLOGY DEPT.	品质部 QUALITY DEPT.	采购部 PURCHASING DEPT.

Date: April 3, 2023

深圳市炬烜科技有限公司

CHIP SUN TECHNOLOGY CO.，LTD

地址 ADD: 深圳市龙华新区大浪腾龙路淘金地电子商务孵化基地 B 座 206

Rm. Rm 206, Tower B, Taojindi Building, Tenglong Road, Dalang Street, Longhua New District, Shenzhen, China

电话 TEL: 86-755-83458796　传真 FAX: 86-755-83459818

网址 WEB ADD: http://www.chinachipsun.com

E-MAIL: sales01@chinachipsun.com

Rev	Revise page	Revise contents	Date	Ref.No.	Reviser
A1	ALL	Initial released	2023.04.03	N/A	DavidJiang

1. QUARTZ CRYSTAL UNIT SPECIFICATION

Parameter	Sign	Specification
1.1 Nominal Frequency :	F0	16.000MHz
1.2 Holder type :	-	FTX321S（SMD3225 SEAM TYPE）
1.3 Mode of oscillation :	-	Fundamental
1.4 Frequency tolerance :	FL	±30ppm at 25℃±3℃
1.5 Equivalent resistance :	RR	50ohms max.
1.6 Operating temperature range :	T_{OPR}	-40℃ To +85℃
1.7 Storage temperature range :	T_{STG}	-55°C To +125°C
1.8 Frequency Stability :	TC	±30ppm at -40℃ To +85℃
1.9 Loading capacitance :	CL	20pF
1.10 Drive level :	DL	10 uW Typical, 100uW max.
1.11 Shunt Capacitance :	C0	2.0pF max.
1.12 Insulation resistance :	IR	More than 500MΩ at DC 100V
1.13 Circuit:	-	Measured in HP/E5100A,S&A 250B
1.14 Aging :	Fa	±3ppm max. (+25°C 1st Year)
1.15 Dimensions and marking :		Refer to page.3
1.16 Emboss carrier tape & reel :		Refer to page.5 and page.6
1.17 Note :		

Standard atmospheric conditions

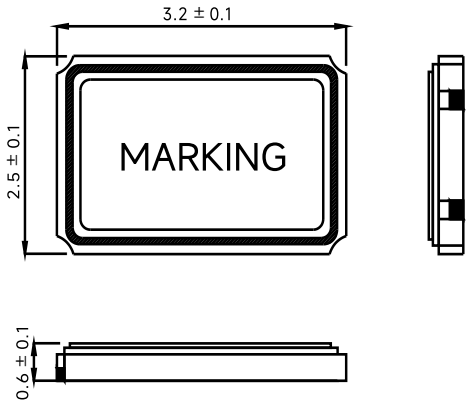
Unless otherwise specified, the standard range of atmospheric conditions for making measurement and tests are as follow:

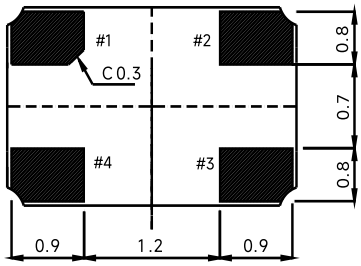
Ambient temperature : 25±3°C

Relative humidity : 40%~70%

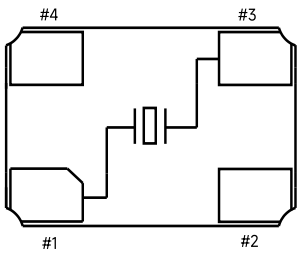
2. FTX321S MARKING & DIMENSIONS

(UNIT: mm)

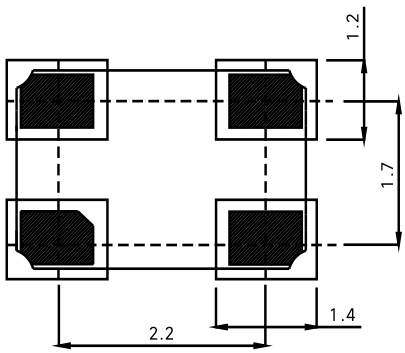




Marking #2, #4 is connected with metal cap of top.



<TOP VIEW>



Recommended Solder Pad

*Marking should be printed as following:

Logo, Nominal Frequency

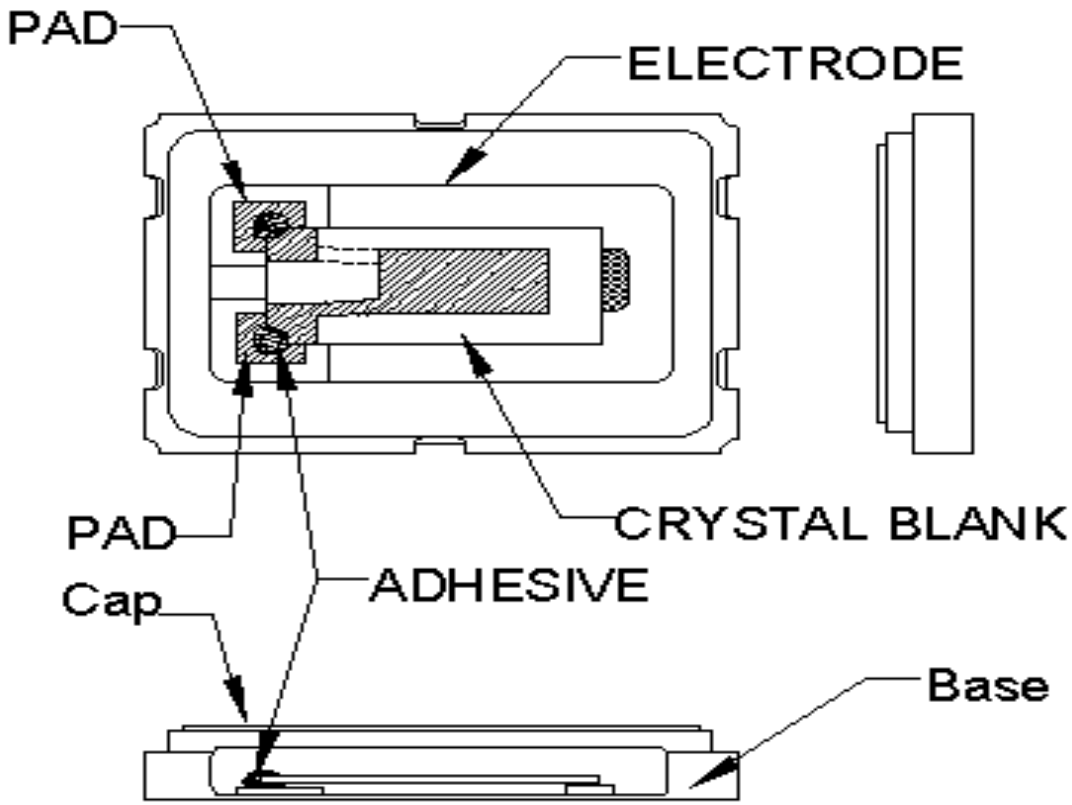
*Manufacturing Logo: FT

*Nominal frequency = 3 number after decimal point MAX.

(ex. 16.000 MHz → 16.000)

Marking: Laser marking

3. INSIDE STRUCTURE



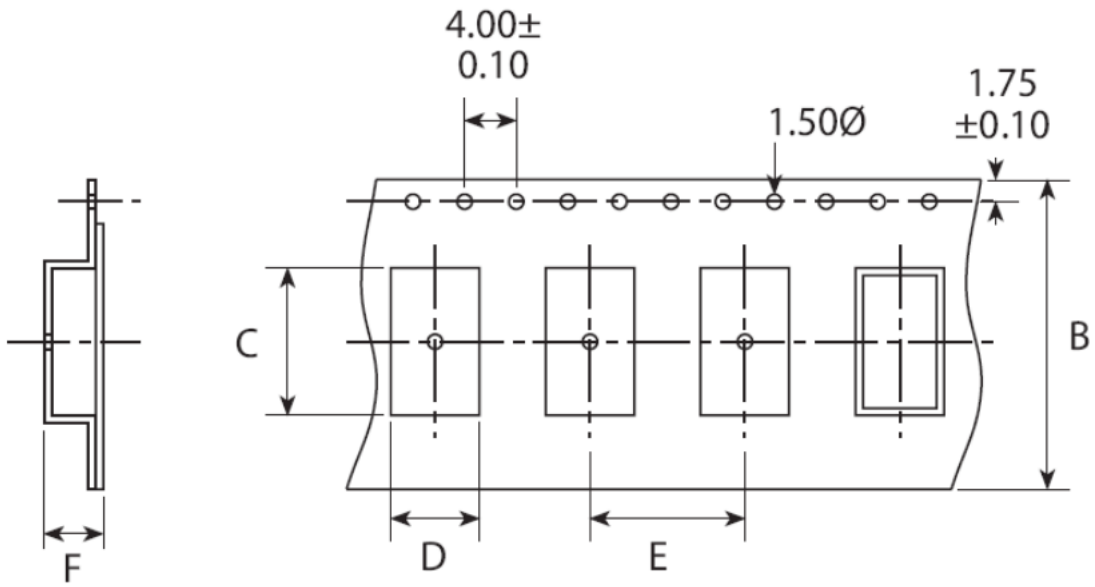
Reference drawing

Base: Alumina Ceramic (Al_2O_3) Metallized Pad: W Ni Plating Au Plating
Cap: Fe-Ni
(3) Crystal Enclosure Seal: Seal Seam
(4) Crystal Blank Rectangular At-Cut Quartz Crystal Blank
(5) Adhesive Silver Conductive Polyimide Resin
(6) Electrode Ag
(7) PAD

Alumina Ceramic (W. Ni. Au)

4. FTX321S EMBOSS CARRIER TAPE & REEL

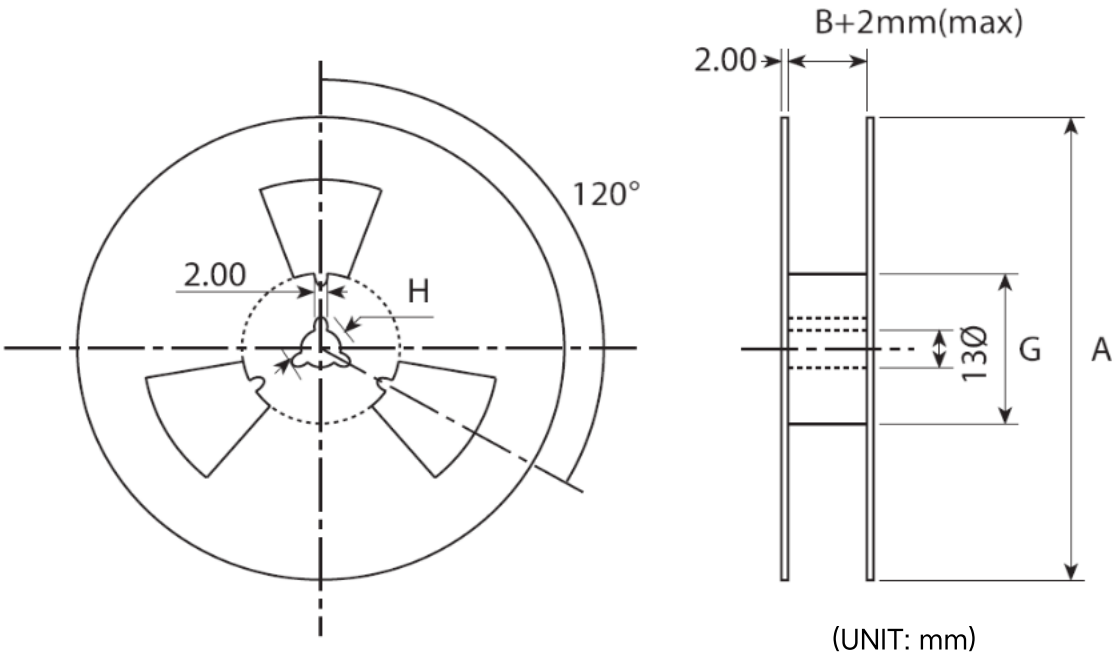
a.) Dimensions of Carrier Tape



	A	B	C	D	E	F	G
SMD3225	178 ± 2.0	8.0 ± 0.3	3.5 ± 0.1	2.8 ± 0.1	4.0 ± 0.1	1.4 ± 0.1	60.5 ± 1.0

(UNIT: mm)

b.) Dimensions of Reel



(UNIT: mm)

c.) Storage condition

Temperature: +40deg.C Max.

Relative Humidity: 80% Max.

d.) Standard packing quantity

3,000PCS / REEL

e.) Material of the tape

Tape	Material
Carrier tape	A – PET
Top tape	Polyester

f.) Label contents

.The type of product

.Our specification No.

.Your Part No.

.Lot No.

.Nominal Frequency

.Quantity

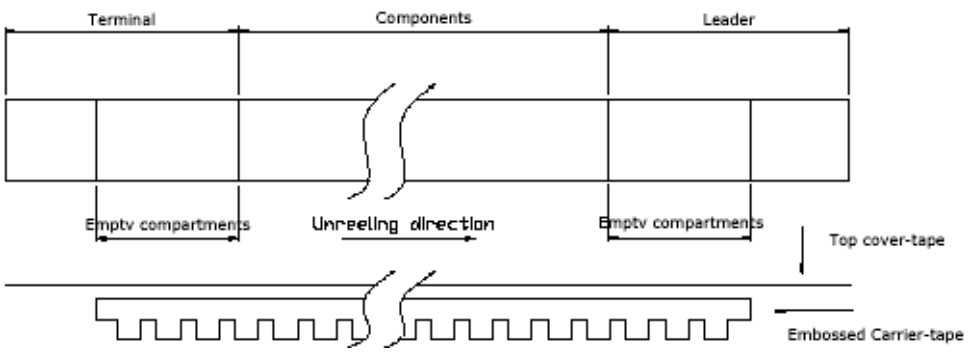
.Our Company Name

Sticks label for every reel.

PART NUMBER	
PO NO	
PR. NO:	
HOLDER TYPE	
FREQUENCY	
REMAKS	
QUANTITY	
CHIP SUN TECHNOLOGY CO., LTD	

g.) Taping dimension

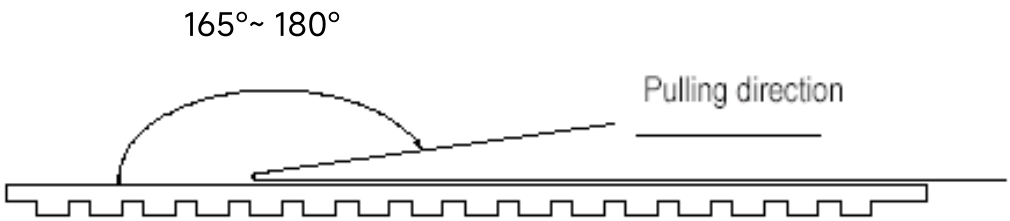
Leader	Cover-tape	The length of cover-tape in the leader is more than 400 mm including empty
	Carrier-tape	After all products were packaged, must remain more than twenty pieces or
Termina l	Cover-tape	The tip of cover-tape shall be fixed temporary by paper tape and roll around
	Carrier-tape	The empty embossed area which are sealed by top cover-tape must remain



h.) Joint of tape

The carrier-tape and top cover-tape should not be jointed.

i.) Release strength of cover tape
It has to between 0.1N to 0.7N under following condition.
Pulling direction 165° to 180°
Speed 300mm/min.
Otherwise unless specified.



Other standards shall be based on JIS C 0806-1990.

5. Mechanical Endurance: Provided that measurement shall be carried out afterletting it alone in the room temperature for 1 hour.

	Item	Conditions	Specifications
5.1	Drop	Fall freely from 100 cm of height 3 times on a firm wood	MIL-STD-202F-203B
5.2	Mechanical Shock	Device are shocked to half sine wave (1000 G) three mutually perpendicular axes each 3 times.	MIL-STD-202F
5.3	Vibration	(1)Vibration Frequency: 10~55Hz (2)Cycle: 1 to 2 Min. (3)Full Cycle: 1.5mm P-P. (4)Direction: X.Y.Z (5)Time: 2 Hours / Each Direction	MIL-STD-883E
5.4	Substrate Bending	Mount the specimen on substrate. Apply the following pressure Direction: see Fig –1 Speed: 0.5 mm/sec Hours: 5 ± 1 sec Amount of substrate: 3 mm Max.	Without mechanical damage such as breaks. Without electrode peeling. Electrical characteristics shall be satisfied.
5.5	Adhesion	Mount the specimen on substrate. Apply the following pressure Direction: see Fig –2 Weight: 10N Hours: 10 ± 1 sec	

5.6	Body strength	Mount the specimen on substrate. Apply the following pressure Direction: see Fig –3 Weight: 10N Hours: 10 ± 1 sec	
5.7	Seal	Fine Leak: 4.5kgf/cm^2 2hours 1×10^{-9} Pa.m^3/sec Gross Leak: 4.5kgf/cm^2 2hours 1.5×10^{-5} Pa.m^3/sec	MIL-STD-883E

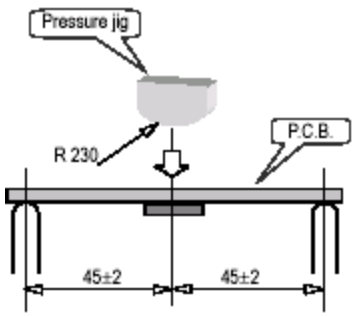


Fig-1

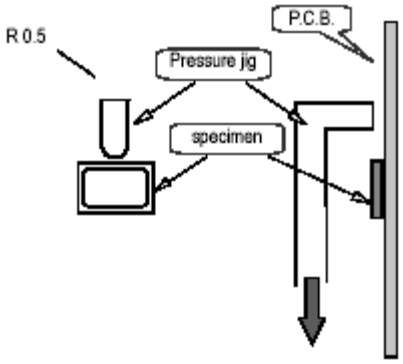


Fig-2

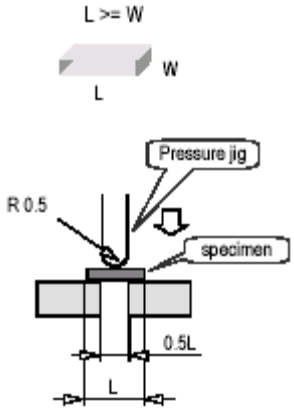
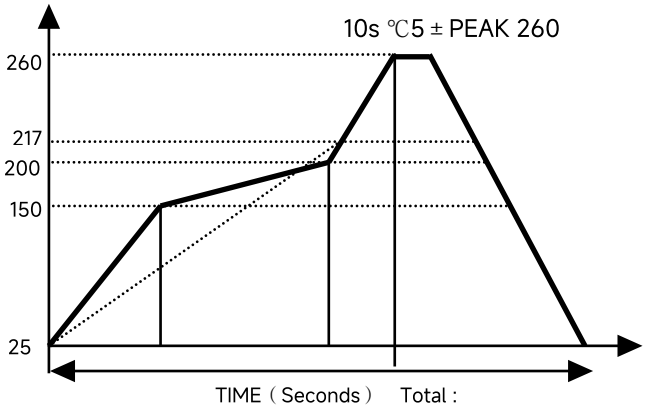


Fig-3

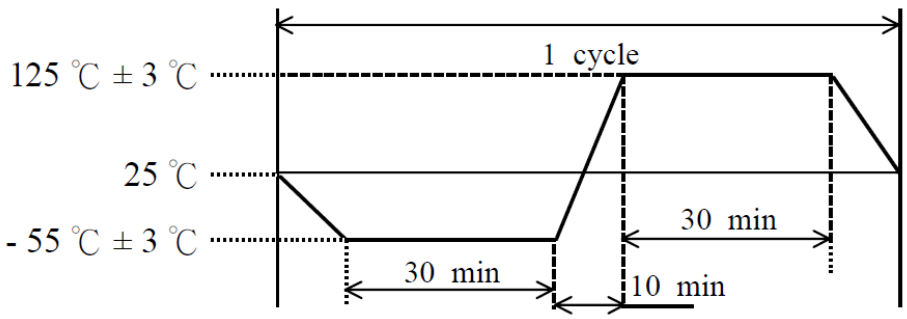
5.8	Solder ability	Pre-heat temperature : +150±10°C Pre-heat time : 60~120s When the temperature of the specimen is reached at +215±3°C, it shall be left for 30±1sec. Peak temperature 240±5°C Material: Pb-free (Sn-3.0Ag-0.5Cu) Flux : Rosin resin methyl alcohol solvent (1:4) The electrodes should be covered by a new solder at least 90% of immersed area.	MIL-STD-883E 2003

5.9	Resistance to Soldering Heat	Run in Reflow Reflow soldering shall be allowed Only two(2) time. **Available for Lead Free Soldering**  (1) Preheat 160~180 deg.C 120sec. (2) Primary heat 220 deg.C 60sec. (3) Peak 260 deg.C 10sec. Max.	MIL-STD-202F

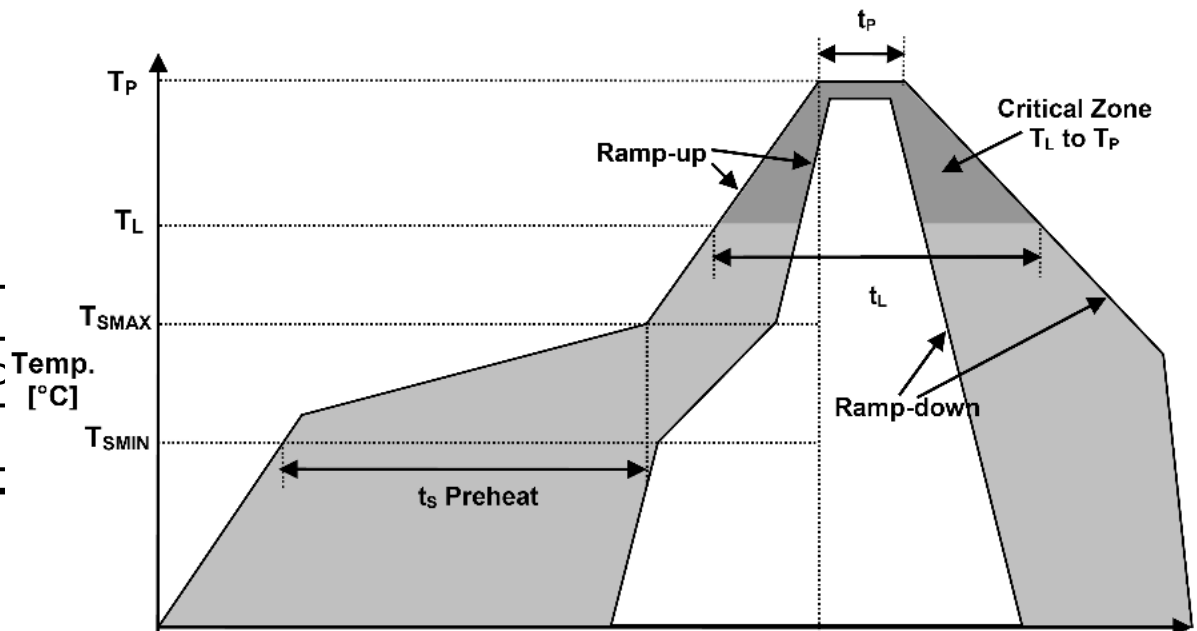
6. Environmental Endurance: Provided that measurement shall be carried out afterletting it alone in the room temperature for 1 hour.

	Item	Conditions	Specifications
6.1	Humidity	+60°C±2°C,RH 80~85%, Duration of 500 hours. The units are then allowed to stand for approx 2 hours in room temperature before checking	MIL-STD-202F

6.2	Storage in Low Temperature	Temperature: -40±2°C , Duration of 500 hours. The units are then allowed to stand at room temperature for approx 2 hours before checking.	MIL-STD-883E
6.3	Storage in High Temperature	Temperature:+85°C±2°C, Duration of 500 hours. The units are then allowed to stand at room temperature for approx 2 hours before checking.	MIL-STD-883E
6.4	Thermal Shock	Temperature 1: -55°C±5°C Temperature 2: 125°C±5°C Temperature change between T1 and T2 at soonest Run 100 cycles, maintain T1 and T2 30minutes each in one cycle (Refer to Fig-4)	MIL-STD-883E



7. Recommended Solder Reflow Profile



Temperature Min Preheat	T_{SMIN}	150°C
Temperature Max Preheat	T_{SMAX}	175°C
Time (T_{SMIN} to T_{SMAX})	t_S	60-180 sec.
Temperature	T_L	217°C
Peak Temperature	T_P	260°C
Ramp-up rate	R_{UP}	3°C/sec max.
Ramp-down rate	R_{DOWN}	6°C/sec max.
Time within 5°C of Peak Temperature	t_P	10 sec max.
Time t[25°C] to Peak Temperature	t[25°C] to Peak	480 sec max.
Time	t_L	60-150 sec.